NSN 5962-01-005-9331

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Body Length:
Between 0.755 inches and 0.785 inches
Body Width:
Between 0.265 inches and 0.291 inches
Body Height:
Between 0.150 inches and 0.199 inches
Maximum Power Dissipation Rating:
600.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs and w/open collector and schottky and w/decoded output and w/storage and
w/enable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Gold
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Ram
Precious Material And Location:
Terminal surface gold
Precious Material:
Gold
Test Data Document:
35351-151438 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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